

Parameters Subject to Change Without Notice

DESCRIPTION

The JWB19816 is a linear LED driver with power MOSFET integrated, and the output current is set by the external resistor. Patented current control strategy ensures low output current ripple and high accuracy while the system is simple with few external components and very low BOM cost.

JWB19816 provides over temperature protection. When temperature inside chip exceeds OTP_{CHIP} , JWB19816 decreases LED current, which can help chip cooling.

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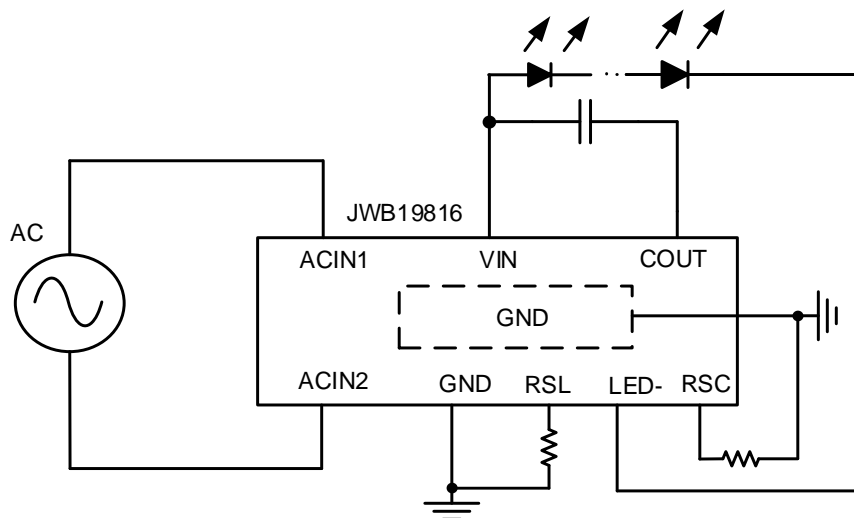
FEATURES

- 800V Bridge Rectifier Integrated
- 600V JFET & 500V MOSFET Integrated
- High-accuracy Output Current
- Over Temperature Protection
- Meet the IEC61000-3-2_2018 Standard
- Meet the requirements of SVM <0.4, Pst_LM <1, DF> 0.7
- No EMI Issues
- Low BOM Cost
- HSOP-8 Package

APPLICATIONS

- LED Bulb
- Other LED Lighting

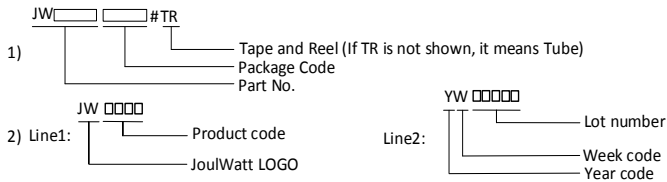
TYPICAL APPLICATION



ORDER INFORMATION

| DEVICE ¹⁾ | PACKAGE | TOP MARKING ²⁾ | ENVIROPNMENTAL ³⁾ |
|----------------------|---------|---------------------------|------------------------------|
| JWB19816HSOPD#TR | HSOP-8 | JWB19816 YW□□□□□ | GREEN |

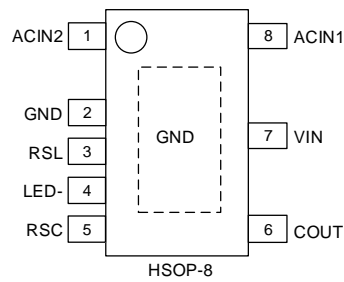
Notes:



3) All JoulWatt products are packaged with Pb-free and Halogen-free materials and compliant to RoHS standards.

PIN CONFIGURATION

TOP VIEW



ABSOLUTE MAXIMUM RATING¹⁾

| | |
|---|-----------------|
| VIN Pin..... | 600V |
| LED- Pin..... | 500V |
| COU _T Pin..... | 500V |
| RSL&RSC Pin..... | -0.4V to 8V |
| I _{out_max} @ T _j = 150 °C..... | 100mA |
| Junction Temperature ²⁾³⁾ | 150°C |
| Lead Temperature | 260°C |
| Storage Temperature | -65°C to +150°C |

RECOMMENDED OPERATING CONDITIONS

| | |
|--|----------------|
| VIN..... | 500V |
| LED-..... | 400V |
| COU _T | 400V |
| I _{out} | 60mA |
| Junction Temperature (T _j) | -40°C to 125°C |

THERMAL PERFORMANCE⁴⁾

| | | |
|-------------|---------------|---------------|
| | θ_{JA} | θ_{JC} |
| HSOP-8..... | 50..... | 10°C/W |

Notes:

- 1) Exceeding these ratings may damage the device. These stress ratings do not imply function operation of the device at any other conditions beyond those indicated under RECOMMENDED OPERATING CONDITIONS.
- 2) The JWB19816 includes thermal protection that is intended to protect the device in overload conditions. Continuous operation over the specified absolute maximum operating junction temperature may damage the device.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.

ELECTRICAL CHARACTERISTICS

$T_a = 25\text{ }^\circ\text{C}$, unless otherwise stated.

Advance Information, not production data, subject to change without notice.

| Item | Symbol | Condition | Min. | Typ. | Max. | Unit. |
|---|-----------------|---|------|------|------|------------------|
| VIN Maximum Voltage | V_{IN_BV} | $I_{OUT}=0\text{mA}, V_{IN}=150\text{uA}$ | 600 | | | V |
| LED- Maximum Voltage | V_{LED_BV} | $I_{OUT}=0\text{mA}, LED-=150\text{uA}$ | 500 | | | V |
| COOUT Maximum Voltage | V_{COOUT_BV} | $I_{OUT}=0\text{mA}, COOUT=150\text{uA}$ | 500 | | | V |
| VIN Quiescent Current | I_Q | $V_{IN}=15\text{V}, RSL=5\text{V}, RSC=5\text{V}$ | | | 200 | μA |
| VIN Over Voltage Protection Threshold | V_{IN_SUR} | | | 420 | | V |
| VIN Over Voltage Protection Time | T_{SUR} | | | 2.56 | | mS |
| LED- Channel Reference Voltage | V_{REF} | | 580 | 600 | 620 | mV |
| COMP Voltage ⁵⁾ | V_{COMP} | | | 0.17 | | V |
| Bridge Diode BV Voltage ⁵⁾ | V_{BR_BD} | | 800 | | | V |
| Bridge Diode Forward Voltage Drop ⁵⁾ | V_{F_BD} | $I_F=1\text{A}$ | | | 1.1 | V |
| Bridge Diode Average Forward Current ⁵⁾ | $I_{F(AV)}$ | | | | 0.5 | A |
| Bridge Diode Peak Forward Surge Current 1ms Single Half Sine Wave | I_{FSM} | | | | 30 | A |
| Thermal Protection Threshold ⁵⁾ | OTP_{CHIP} | | 140 | 150 | 160 | $^\circ\text{C}$ |

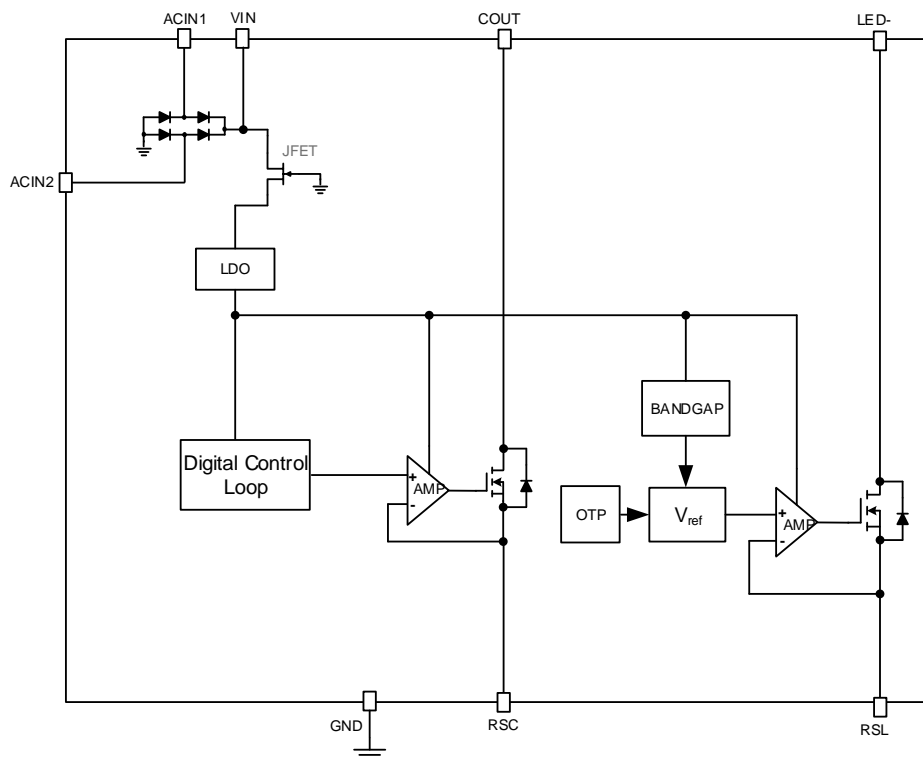
Notes:

5) Guaranteed by design

PIN DESCRIPTION

| Pin HSOP-8 | Name | Description |
|------------|-------|--|
| 1 | ACIN2 | AC input |
| 2 | GND | Chip ground |
| 3 | RSL | LED current setup pin |
| 4 | LED- | LED current output pin |
| 5 | RSC | Electrolytic Capacitor (E-Cap) current setup pin |
| 6 | COUT | E-Cap current output pin |
| 7 | VIN | Power supply pin |
| 8 | ACIN1 | AC input |

BLOCK DIAGRAM



FUNCTIONAL DESCRIPTION

JWB19816 is a double channel Linear LED driver for direct line operation.

Theory of Operation

The input is the rectified voltage V_{in} from AC line by the internal bridge rectifier. When V_{in} is higher than the forward voltage (VF) of the LEDs, the current of LEDs begins to increase.

The E-Cap charging block works when the V_{in} voltage is higher than the E-Cap voltage. The E-Cap supplies current when the AC mains voltage is lower than the E-Cap voltage to eliminate the LED current ripple. The E-Cap current and LED string current are shown below.

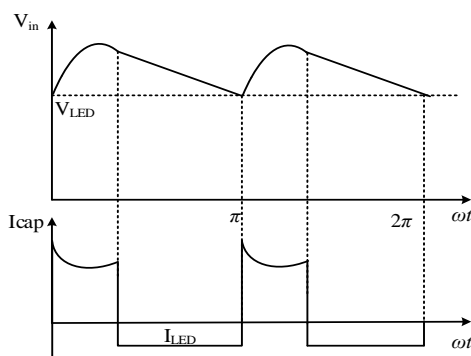


Figure.1 The E-Cap current and LED current

Soft Boot

When the internal VDD reaches 3.9V, the COMP voltage is clamped at V_{COMP} for 80mS in typical, then exits the clamp value.

LED Constant Peak Current Control

JWB19816 controls the LED peak current from the information of the current sensing resistor. The output LED peak current can be calculated as:

$$I_{PEAK} \approx V_{REF}/R_{SL}$$

Where

V_{REF} is the reference voltage;

R_{SL} is the current sensing resistor connected between RSL and chip ground.

VIN Over Voltage Protection

When the VIN voltage is higher than V_{IN_SUR} , the gate of two power MOSFET will be pulled down to zero for T_{SUR} before the next detection.

Over Temperature Protection (OTP)

When the junction temperature of JWB19816 is higher than OTP_{CHIP} , LED current reduces by decreasing the LED- Reference Voltage (V_{REF}). The LED current drop slope is about -15%/10°C after OTP as the figure shown below.

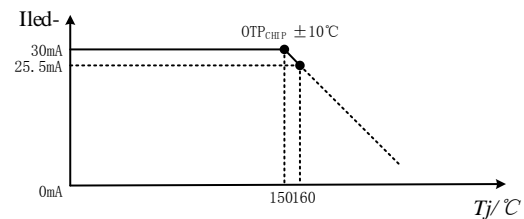


Figure.2 OTP Slope

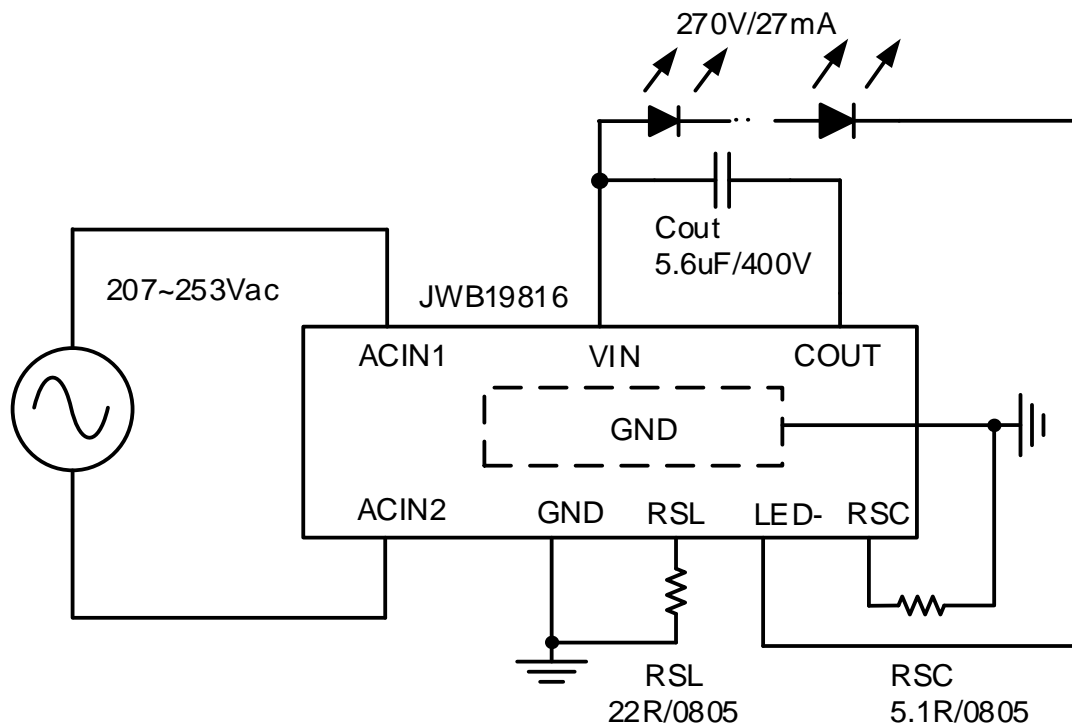
APPLICATION REFERENCE

Note: Information in the following reference design sections is not part of JoulWatt component specification. Customers are responsible for determining suitability of components chosen for their purposes and should validate their design implementation to make sure the proper system functionality.

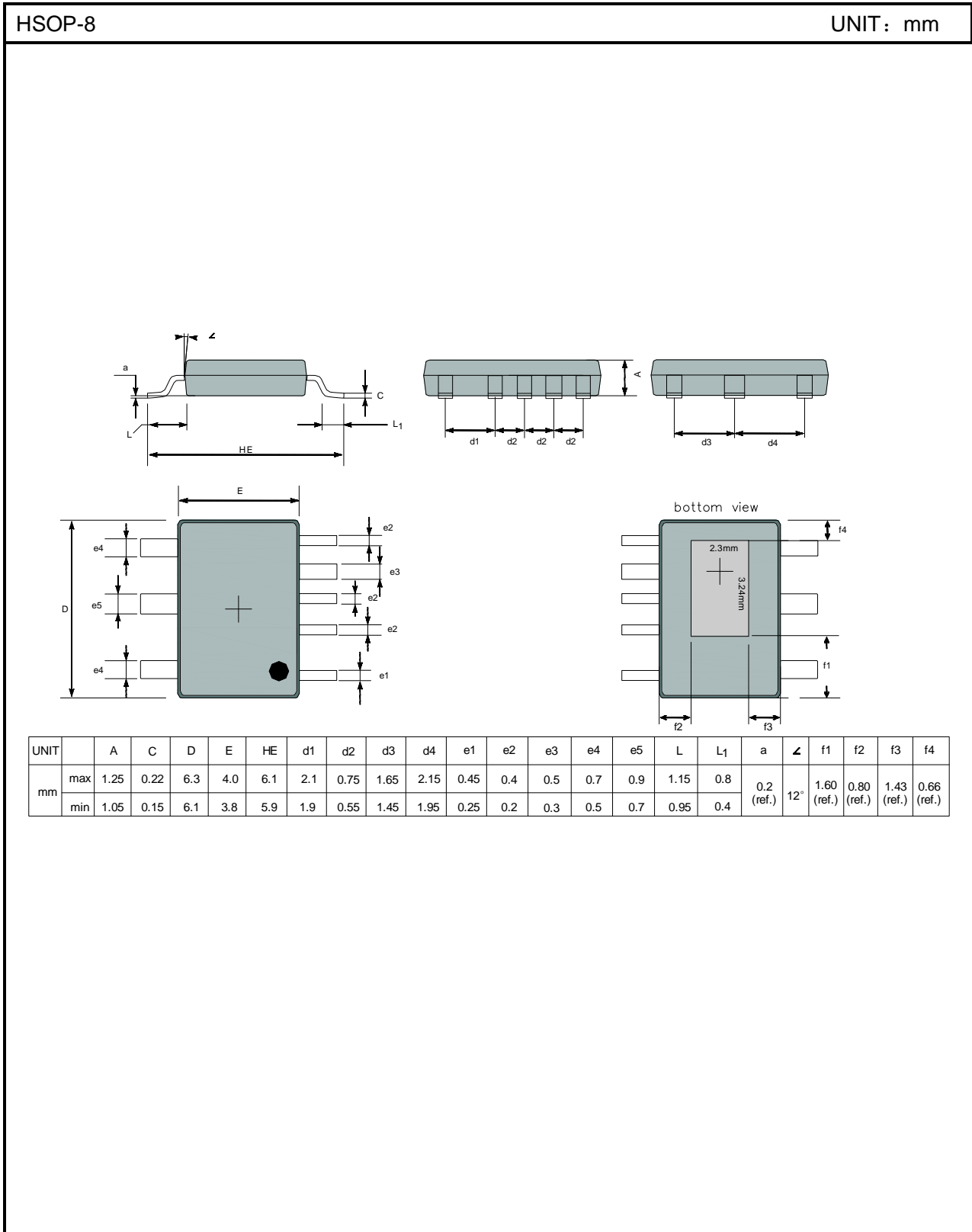
This reference design is suitable for 9W linear LED driver, using JWB19816, with low LED current ripple and high efficiency.

Reference 1:

- V_{IN}: 207VAC~253VAC
- V_{OUT}: 270V
- I_{OUT}: 27mA
- PF: >0.5



PACKAGE OUTLINE



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